

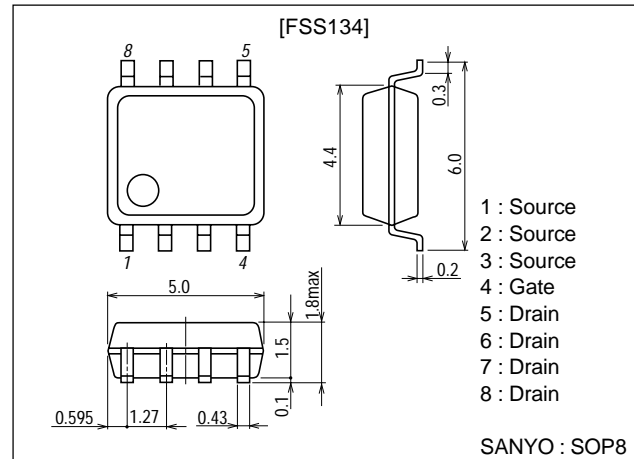
**FSS134****DC/DC Converter Applications****Features**

- Low ON resistance.
- Ultrahigh-speed switching.
- 4V drive.

Package Dimensions

unit:mm

2116

**Specifications****Absolute Maximum Ratings** at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		-30	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		-9	A
Drain Current (pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	-52	A
Allowable Power Dissipation	P_D	Mounted on a ceramic board (1000mm ² ×0.8mm)	2.0	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1\text{mA}$, $V_{GS} = 0$	-30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -30\text{V}$, $V_{GS} = 0$			-1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 16\text{V}$, $V_{DS} = 0$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10\text{V}$, $I_D = -1\text{mA}$	-1.0		-2.4	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10\text{V}$, $I_D = -9\text{A}$	11	17		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = -9\text{A}$, $V_{GS} = -10\text{V}$		16	21	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D = -4\text{A}$, $V_{GS} = -4.5\text{V}$		24	34	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D = -4\text{A}$, $V_{GS} = -4\text{V}$		26	37	$\text{m}\Omega$

Marking : S134

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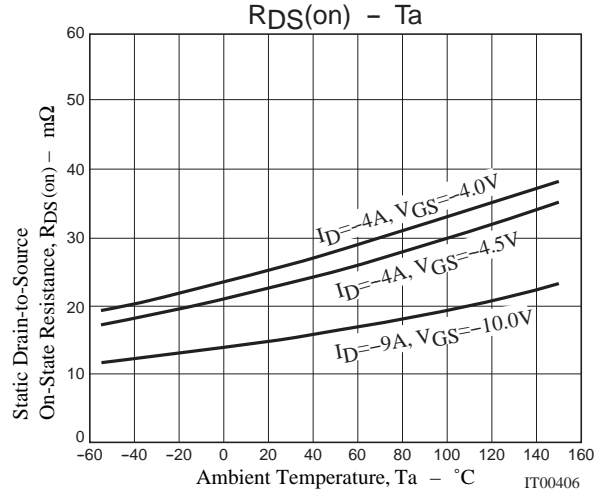
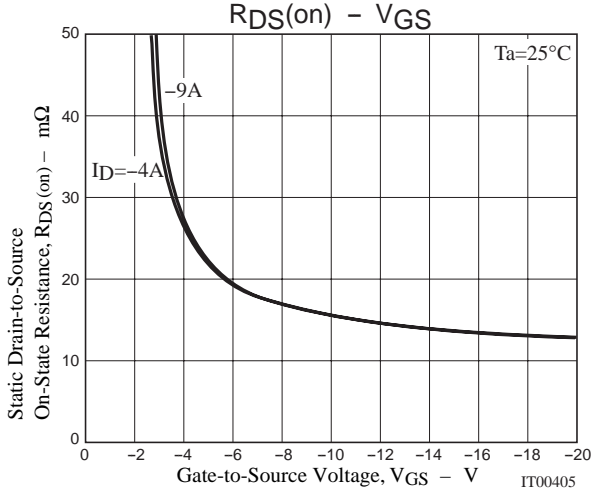
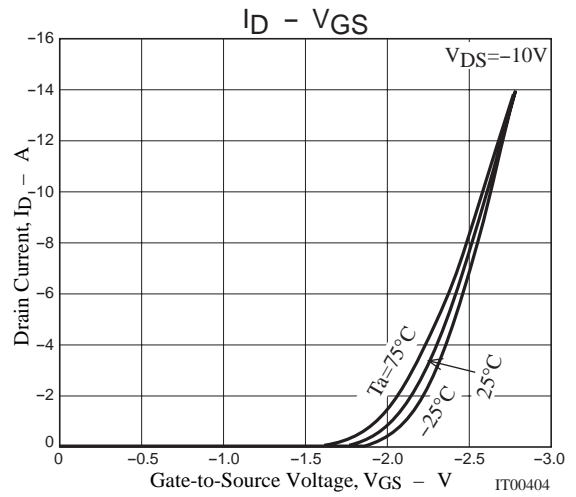
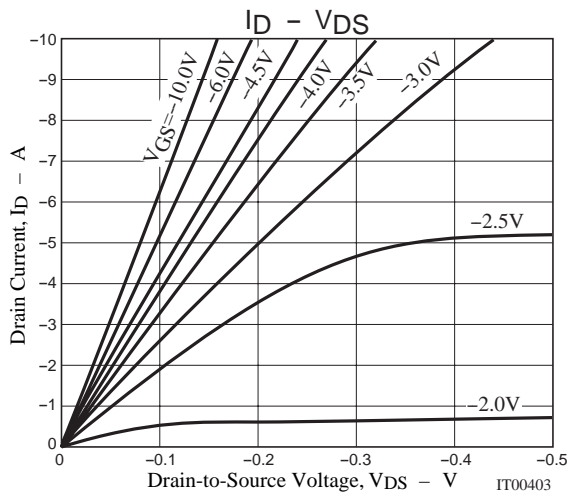
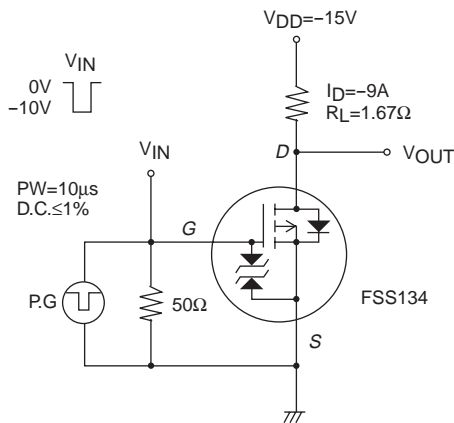
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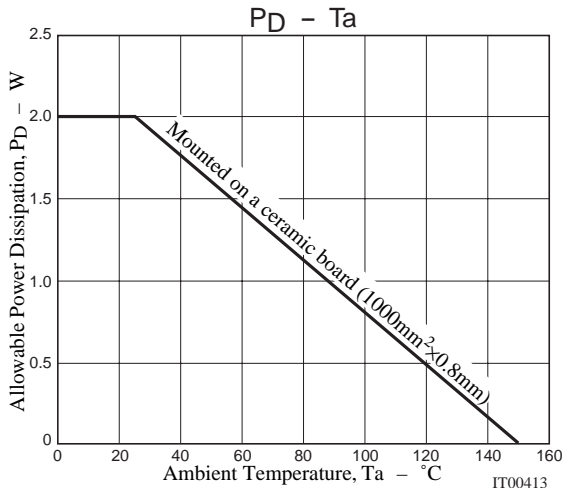
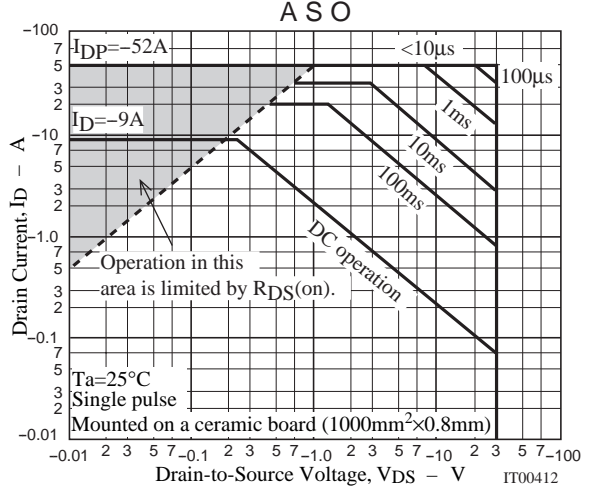
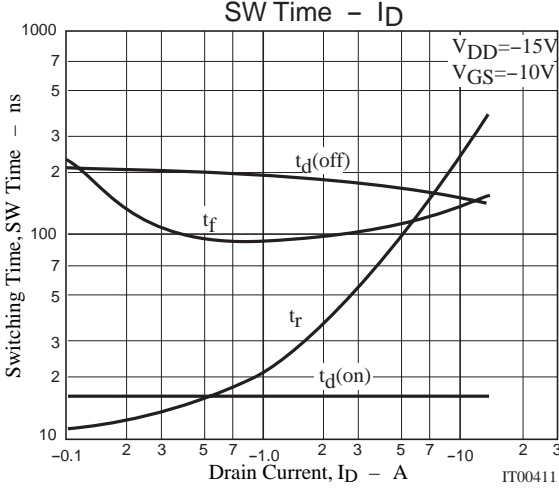
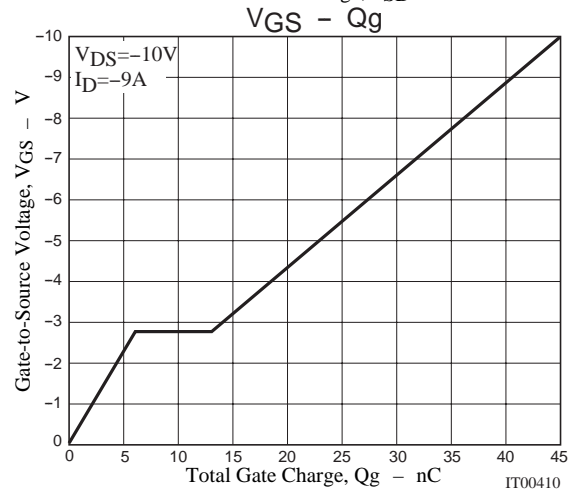
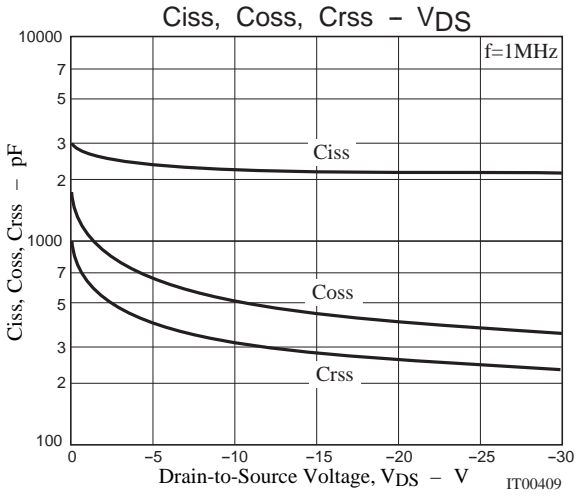
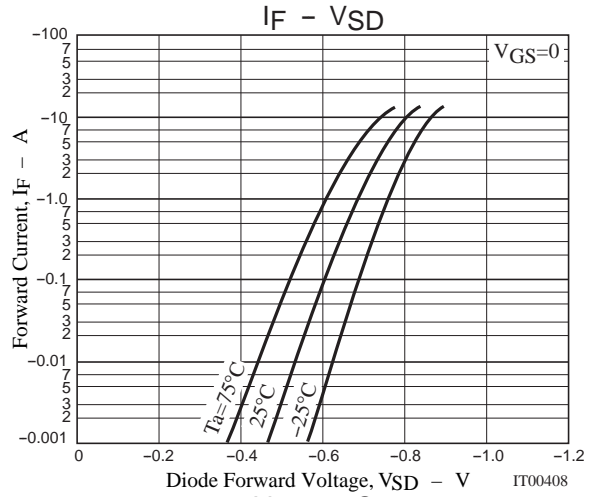
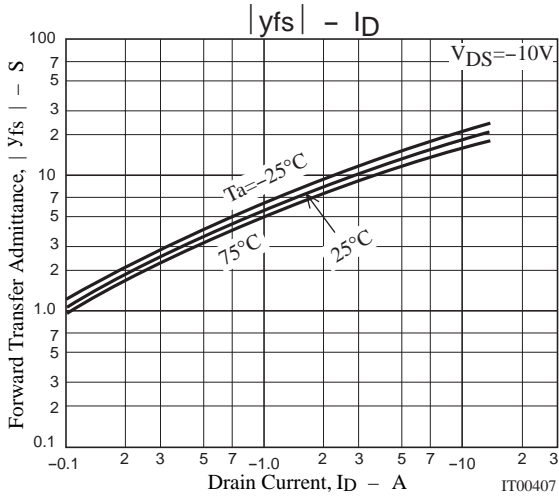
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	$V_{DS}=-10V, f=1MHz$		2300		pF
Output Capacitance	Coss	$V_{DS}=-10V, f=1MHz$		520		pF
Reverse Transfer Capacitance	Crss	$V_{DS}=-10V, f=1MHz$		320		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		17		ns
Rise Time	t_r	See specified Test Circuit		220		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		160		ns
Fall Time	t_f	See specified Test Circuit		130		ns
Total Gate Charge	Qg	$V_{DS}=-10V, V_{GS}=-10V, I_D=-9A$		45		nC
Gate-to-Source Charge	Qgs	$V_{DS}=-10V, V_{GS}=-10V, I_D=-9A$		6		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=-10V, V_{GS}=-10V, I_D=-9A$		7		nC
Diode Forward Voltage	V_{SD}	$I_S=-9A, V_{GS}=0$		-0.8	-1.5	V

Switching Time Test Circuit



FSS134



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